

CMOS 3.2 x 2.5 x 1.4mm SMD

nA Current 32.768kHz

- Miniature 3.28 x 2.5mm SMD package
- Frequency: 32.768kHz
- Very low current consumption, 0.79μA at 1.8V supply
- Supply voltage 1.8, 2.5, 3.0, 3.3 or 5.0 Volts
- Frequency stability ±5ppm over -40 to +85°C

DESCRIPTION

EME32T series TCXOs are packaged in a miniature 4 pad ceramic SMD package. Low current consumption with squarewave (CMOS) output, tolerance is ± 5.0 ppm over -40° to $+85^{\circ}$ C.

SPECIFICATION

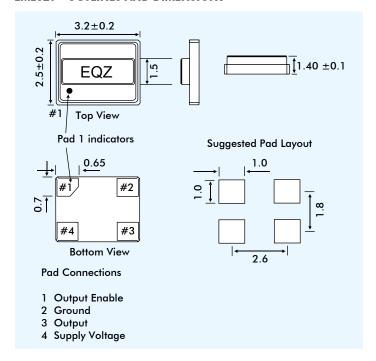
| SI EGII ICATION | |
|--------------------------------|--|
| Product Series Code: | EME32T |
| Output Waveform: | CMOS Squarewave |
| Initial Calibration Tolerance: | ±2.5ppm (at t. 25°±3°C) |
| Frequency Stability: | -10° to +60°C: ±3.8ppm -40° to +85°C: ±5.0ppm -40° to +105°C ±8.0ppm |
| Timing error over time: | ±0.432 s/day ±12.960 s/month ±2.628 m/year (T = 25°C) |
| Frequency Stability | |
| vs. Ageing: | ±3.0 ppm max. first year |
| vs. Load Change: | ±0.2 ppm max. ±10% change |
| vs. Reflow: | ±3ppm max. for one reflow |
| | (Measured after 24 hours) |
| vs. All range of Vdd: | ±1.0ppm/Volt max. |
| Output Logic / Output Load: | CMOS / 15pF |
| Output Voltage Level 'HIGH': | 90% of Vdd |
| Output Voltage Level 'LOW': | 10% of Vdd |
| Rise and Fall Times: | 100ns max. |
| Duty Cycle: | 50%±10% typical |
| Start-up Time: | 1s max. at 25°C |
| | 3s max. Over -40° to +85°C |
| Pad 1 OE Thresholds: | Vih = 0.8*Vdd, $Vil = 0.2*Vdd$ |
| Current Cnsumption: | 1.0uA (typ.), 2.0uA (max.) |







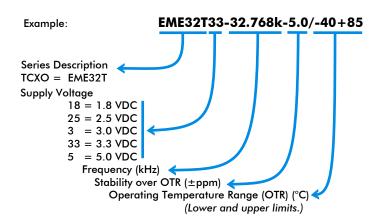
EME32T - OUTLINES AND DIMENSIONS



POWER SUPPLY VOLTAGE

| Supply Voltage | Tolerance |
|----------------|-----------|
| 1.8V | ±5% |
| 2.5V | ±5% |
| 3.0V | ±5% |
| 3.3V | ±5% |
| 5.0V | ±10% |

PART NUMBERING PROCEDURE



Issue 5